## DESCRIPTION

The SC1628 is a high performance step-up DC-DC converter, designed to drive an external power switch to generate programmable positive voltages. In the particularly suitable LCD contrast bias and flash memory programming power supply applications, typical full load efficiencies are $85 \%$ to $95 \%$. The 4 V to 24 V input operation range allows the SC1628 to be powered directly by the battery pack in most batterypowered applications for greater efficiency. The output voltage can be scaled to 40 V or greater by two external resistors. A pulse-frequency modulation scheme is employed to maintain high efficiency conversion under wide input voltage ranges. Quiescent current is about $100 \mu \mathrm{~A}$ and can be reduced down to $8 \mu \mathrm{~A}$ in shutdown mode. With a switching frequency range of 90 kHz to 250 kHz , small size switching components may be used, which is ideal for battery powered portable equipment such as notebook and palmtop computers.

## APPLICATIONS

- Flash memory programming power supply
- Positive LCD contrast bias for notebook and palmtop computers
- Step-up DC-DC converter module
- Telecom power supply


## ORDERING INFORMATION

| DEVICE $^{(1)}$ | PACKAGE |
| :---: | :---: |
| SC1628CS | SO-8 |

Note:
(1) Add suffix 'TR' for tape and reel.

## PIN CONFIGURATION



## FEATURES

- 4 V to 24 V input voltage operation
- Adjustable output voltage
- Low quiescent current at $100 \mu \mathrm{~A}$
- Pulse-skipping and pulse-frequency modulation maintain high efficiency (max. 95\%)
- 90 kHz to 250 kHz oscillator frequency
- Power-saving shutdown mode ( $8 \mu \mathrm{~A}$ typical)
- Push-pull driver output


## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Maximum | Units |
| :--- | :---: | :---: | :---: |
| Supply Voltage | $\mathrm{V}_{\text {IN }}$ | 24 | V |
| SHDN Voltage | $\mathrm{V}_{\text {SHDN }}$ | 15 | V |
| Operating <br> Temperature Range | $\mathrm{T}_{\mathrm{A}}$ | 0 to 70 | ${ }^{\circ} \mathrm{C}$ |
| Storage <br> Temperature Range | $\mathrm{T}_{\text {STG }}$ | -65 to 125 | ${ }^{\circ} \mathrm{C}$ |

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## ELECTRICAL CHARACTERISTICS

Unless otherwise specified, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\text {IN }}=13 \mathrm{~V}$

| Parameter | Conditions | Min | Typ | Max | Units |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Input Voltage |  | 4 |  | 24 | V |
| Quiescent Current | $\mathrm{V}_{\text {FB }}=1.5 \mathrm{~V}$ |  | 100 | 200 | $\mu \mathrm{~A}$ |
| Shutdown Mode Current | $\mathrm{V}_{\text {SHDN }}=0 \mathrm{~V}$ |  | 8 | 20 | $\mu \mathrm{~A}$ |
| $\mathrm{~V}_{\text {REF }}$ Voltage | $\mathrm{I}_{\text {SOURCE }}=250 \mu \mathrm{~A}$ | 1.16 | 1.22 | 1.28 | V |
| $\mathrm{~V}_{\text {REF }}$ Source Current |  | 250 |  |  | $\mu \mathrm{~A}$ |
| DLOW "ON Resistance" |  |  | 15 |  | $\Omega$ |
| DHI "ON Resistance" |  |  | 10 |  | $\Omega$ |
| CL Threshold |  | 45 | 60 | 75 | mV |
| Shutdown Threshold | $\mathrm{V}_{\text {IN }}-\mathrm{V}_{\text {CL }}$ | 0.8 | 1.5 | 2.4 | V |
| Shutdown Input Leakage Current | $\mathrm{V}_{\text {SHON }}<15 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{~A}$ |

## TYPICAL APPLICATIONS

Color LCD Contrast Bias Supply



Flash Memory Programming Supply



## TYPICAL APPLICATIONS (cont.)

2-Cells to +12V Flash Memory Programmer


4-Cells to +30V Low Power Supply


Telecom +5V Supply





## DEVICE OUTLINE - SO-8



| DIMENSIONS |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DIM $^{N}$ | INCHES |  | MM |  | NOTE |
|  | MIN | MAX | MIN | MAX |  |
| A | .188 | .197 | 4.80 | 5.00 |  |
| B | .149 | .158 | 3.80 | 4.00 |  |
| C | .228 | .244 | 5.80 | 6.20 |  |
| D | .050 | BSC | 1.27 | BSC |  |
| E | .013 | .020 | 0.33 | 0.51 |  |
| $F$ | .004 | .010 | 0.10 | 0.25 |  |
| $H$ | .053 | .069 | 1.35 | 1.75 |  |
| $J$ | .011 | .019 | 0.28 | 0.48 |  |
| K | .007 | .010 | .19 | .25 |  |
| $L$ | $0^{\circ}$ | $8^{\circ}$ | $0^{\circ}$ | $8^{\circ}$ |  |
| M | .016 | .050 | 0.40 | 1.27 |  |

## PIN DESCRIPTIONS

PIN 1: $\quad \mathrm{V}_{\mathrm{IN}} \quad 4 \mathrm{~V}$ to 24 V input supply voltage.
PIN 2: $\quad V_{\text {REF }} \quad 1.22 \mathrm{~V}$ reference output. Bypass with a $0.047 \mu \mathrm{~F}$ capacitor to GND.
Sourcing capability is guaranteed to be greater than $250 \mu \mathrm{~A}$.

PIN 3: $\overline{\text { SHDN }}$ Logical input to shutdown the chip: $>1.5 \mathrm{~V}=$ normal operation, GND = shutdown.
Cannot be floating or forced greater than 15V. In shutdown mode DLOW and DHI pins are low.

PIN 4: FB Feedback signal input to comparator. Connecting a resistance R1 to $\mathrm{V}_{\text {Out }}$ and a resistance R2 to GND yields the output voltage:

$$
\mathrm{V}_{\text {OUT }}=\frac{\mathrm{R} 1+\mathrm{R} 2}{\mathrm{R} 2} \times \mathrm{V}_{\text {REF }}
$$

(refer to typical application circuit).

PIN 5: GND Power ground.
PIN 6: DLOW Driver sinking output. Connected to the gate of the external N -channel MOSFET or the base of the NPN bipolar transistor.

PIN 7: DHI Driver sourcing output. Connected to DLOW when using an external N channel MOSFET. When using an external NPN bipolar transistor, connect a base resistance $R_{B}$ from this pin to DLOW. $\mathrm{R}_{\mathrm{B}}$ value depends upon $\mathrm{V}_{\mathbb{I N}}$, the inductor value and the NPN current gain.
PIN 8: CL Current-limit input. The threshold voltage is 60 mV from $\mathrm{V}_{\mathbb{I}}$. This pin clamps the switch peak current under abnormal conditions.

## PIN CONFIGURATION



